## No. of Brinted Pg.: SARDAR PATEL UNIVERSITY

## Sixth Semester B. Sc. Examination

## **Under CBCS**

[52/A.20]

SEAT No.

Wednesday, 4<sup>th</sup> April-2018 Time: 10:00 am To 01:00 pm

Subject: PHYSICS [US06CPHY05]

Digital Electronics, Electronic Communication & VLSI Technology

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Total	Mark	c 7N

N.B:	(i) All	the	symbols	have	their	usual	meanings.
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	(8)	Explain in brief simplex communication with examples.	
	(9)	To achieve 80% modulation of a carrier of V <sub>c</sub> = 40 V, how much modulating	
		signal voltage is required?	
	(10)	Explain briefly different levels of integration of IC chips.	
i in the	(11)	How does the Schottky diode differ from ordinary diode?	
	(12)	State the drawbacks of junction capacitors used in IC.	ı
		and the second of the second o	
Que3	(a)	Define AND gate. Explain the working of the two inputs AND gate with suitable circuit diagram. Which gate is implemented when its output is inverted?	[06]
	(b)	What is an inverter? Describe the circuit action of transistor inverter.	[04]
	• •	OR	الما
		<b>~.</b>	
Que3	(a)	What is meant by TTL? Explain the working of two inputs TTL NAND gate	[06]
		with suitable circuit diagram. Give the values of propagation delay time	1
		and power dissipation of standard TTL gate.	
	(b)	Discuss EX-OR gate with its applications.	[04]
Que4		What is a register? Explain the working of 4 bit shift left register with	[10]
	7.	suitable logic diagram. How it can be converted to shift right register.	
		OR	
Que4		Distinguish between asynchronous and synchronous binary counters. Describe the working of four bit synchronous counter with suitable logic diagram and clocked waveform.	[10]
		aldBrain and clocked waveloilli,	
Que5	(a)	What is amplitude modulation? Explain about mathematical	[06]
•		representation of Amplitude Modulation.	ניטן
	(b)	With necessary diagram, explain the working of AM circuit with a diode.	[04]
		OR	
Que5	(a)	Differentiate between FM and PM with proper diagrams.	[06]
•	(b)	Explain how PM is converted to FM.	[04]
	٠.		[0-4]
Que6	(a)	Describe the fabrication of n-channel JFET in monolithic IC with proper	[06]
<b>4.0.</b> 0	` '	diagrams.	լսսյ
2	(b)	Explain the following configurations of a transistor used for diode	[04]
		operation in the monolithic IC with fabrication diagram;	
, rê		(i) collector – base with emitter floating	
	•	(ii) collector – base with emitter shorted to base.	
		OR	
Que6	(a)	Discuss the structure of base diffused resistor in monolithic IC fabrication`	[06]
		with proper diagram. Also explain concept of sheet resistance.	_ ,
	(b)	Discuss the general classification of integrated circuits and mention their	[04]
5 - 23	1000	advantages over discrete components.	